

ABSTRACT

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in ~~circuits~~ ^{aside} a freely set _^ area of the memory cell to be tested. The arrangement of the column address generator is structured ^{the} same as
5 that of the row address generator wherein both the column address generator and the row address generator receive an add signal from a control circuit, address values from first and second maximum value registers and address values from first and second initial value registers. The column address generator has a comparator which
10 compares an address to be supplied to the memory to be tested with the address value output from the first maximum value register and a selection circuit which selects address to be supplied to the memory using a signal output from the comparator.